Triple 2-channel analog multiplexer/demultiplexerRev. 11 — 9 September 2021Product data sheet

1. General description

The 74HC4053; 74HCT4053 is a triple single-pole double-throw analog switch (3x SPDT) suitable for use in analog or digital 2:1 multiplexer/demultiplexer applications. Each switch features a digital select input (Sn), two independent inputs/outputs (nY0 and nY1) and a common input/output (nZ). A digital enable input (Ē) is common to all switches. When Ē is HIGH, the switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- Wide analog input voltage range from -5 V to +5 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD78 Class II Level B
- Complies with JEDEC standard:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
 - Low ON resistance:
 - 80 Ω (typical) at V_{CC} V_{EE} = 4.5 V
 - 70 Ω (typical) at V_{CC} V_{EE} = 6.0 V
 - 60 Ω (typical) at V_{CC} V_{EE} = 9.0 V
- Logic level translation: to enable 5 V logic to communicate with ±5 V analog signals
- Typical 'break before make' built-in
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

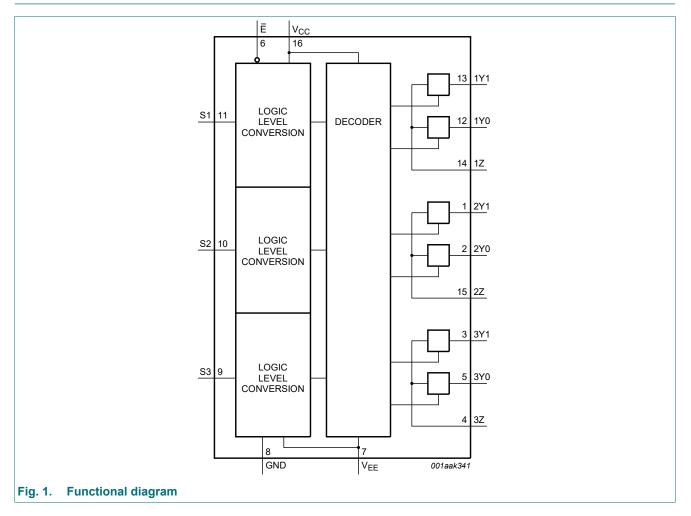
- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating



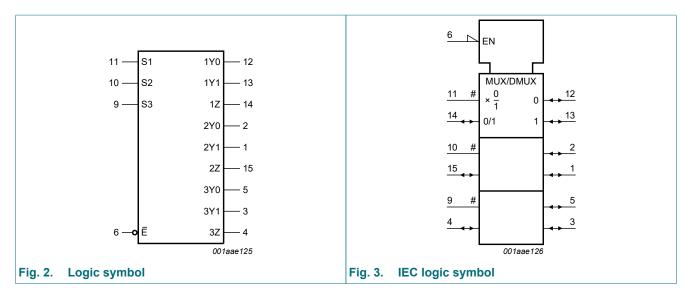
4. Ordering information

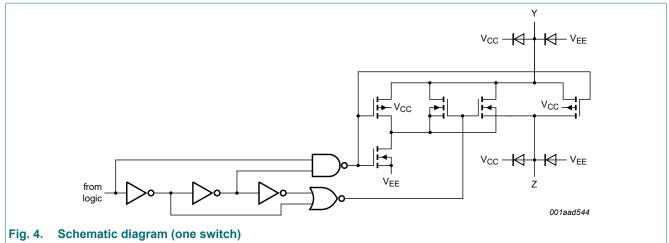
Type number	Package							
	Temperature range	to +125 °CSO16plastic small outline package; 16 leads; body width 3.9 mmto +125 °CTSSOP16plastic thin shrink small outline package; 16 leads; body width 4.4 mmto +125 °CDHVQFN16plastic dual in-line compatible thermal enhanced		Version				
74HC4053D	-40 °C to +125 °C			SOT109-1				
74HCT4053D			body width 3.9 mm					
74HC4053PW	-40 °C to +125 °C	TSSOP16		SOT403-1				
74HCT4053PW	_		body width 4.4 mm					
74HC4053BQ -40 °C to +125 °C [DHVQFN16	Learne and the second and the second se	SOT763-1				
74HCT4053BQ			very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm					

5. Functional diagram

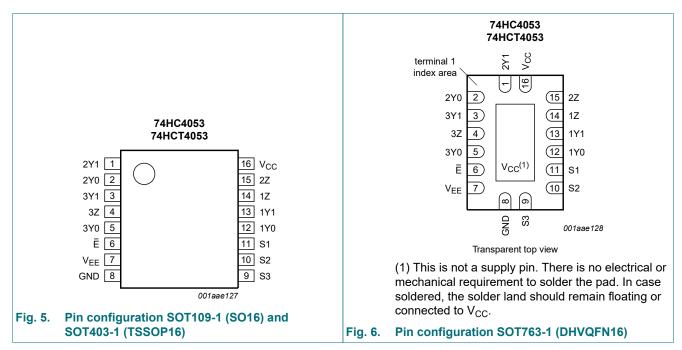


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6. Pinning information



6.1. Pinning

6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
E	6	enable input (active LOW)
V _{EE}	7	supply voltage
GND	8	ground supply voltage
S1, S2, S3	11, 10, 9	select input
1Y0, 2Y0, 3Y0	12, 2, 5	independent input or output
1Y1, 2Y1, 3Y1	13, 1, 3	independent input or output
1Z, 2Z, 3Z	14, 15, 4	common output or input
V _{CC}	16	supply voltage

7. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Inputs		Channel on
E	Sn	
L	L	nY0 to nZ
L	Н	nY1 to nZ
Н	X	switches off

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage	[1]	-0.5	+11.0	V
I _{IK}	input clamping current	V_{I} < -0.5 V or V_{I} > V_{CC} + 0.5 V	-	±20	mA
I _{SK}	switch clamping current	$V_{\rm SW}$ < -0.5 V or $V_{\rm SW}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
I _{SW}	switch current	$-0.5 V < V_{SW} < V_{CC} + 0.5 V$	-	±25	mA
I _{EE}	supply current		-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	[2]	-	500	mW
Р	power dissipation	per switch	-	100	mW

[1] To avoid drawing V_{CC} current out of terminal nZ, when switch current flows into terminals nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no V_{CC} current will flow out of terminals nYn, and in this case there is no limit for the voltage drop across the switch, but the voltages at nYn and nZ may not exceed V_{CC} or V_{EE} .

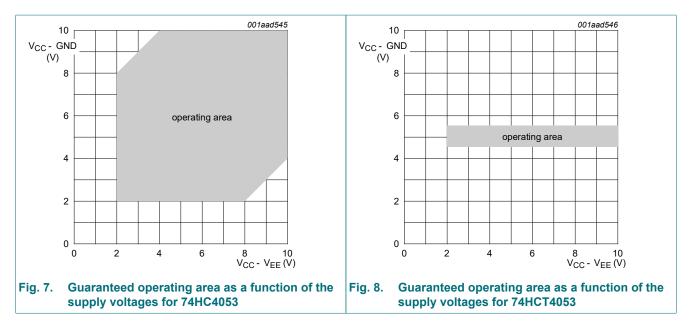
[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C. For SOT763-1 (DHVQFN16) package: P_{tot} derates linearly with 11.2 mW/K above 106 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	7	74HC405	3	7	4HCT405	53	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage	see <u>Fig. 7</u> and <u>Fig. 8</u>							
		V _{CC} - GND	2.0	5.0	10.0	4.5	5.0	5.5	V
		V _{CC} - V _{EE}	2.0	5.0	10.0	2.0	5.0	10.0	V
VI	input voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
V _{SW}	switch voltage		V _{EE}	-	V _{CC}	V _{EE}	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
	rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V
		V _{CC} = 10.0 V	-	-	31	-	-	-	ns/V

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10. Static characteristics

Table 6. R_{ON} resistance per switch for 74HC4053 and 74HCT4053

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see Fig. 9.

Vis is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

For 74HC4053: V_{CC} - GND or V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4053: V_{CC} - GND = 4.5 V and 5.5 V, V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 25	°C						
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	100	180	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	90	160	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	70	130	Ω
R _{ON(rail)}	ON resistance (rail)	V _{is} = V _{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	150	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	80	140	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	70	120	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	60	105	Ω
		V _{is} = V _{CC}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	150	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	90	160	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	80	140	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	65	120	Ω
ΔR _{ON}	ON resistance mismatch	$V_{is} = V_{CC}$ to V_{EE}					
	between channels	V _{CC} = 2.0 V; V _{EE} = 0 V	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	9	-	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V		-	8	-	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	6	-	Ω

74HC_HCT4053

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +85 °C						_
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	225	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	200	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	165	Ω
R _{ON(rail)}	ON resistance (rail)	V _{is} = V _{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	175	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	150	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	130	Ω
		V _{is} = V _{CC}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 µA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	200	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	175	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	150	Ω
T _{amb} = -4	0 °C to +125 °C	,					
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	270	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	240	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	195	Ω
R _{ON(rail)}	ON resistance (rail)	V _{is} = V _{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	210	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	180	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	160	Ω
		V _{is} = V _{CC}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 µA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	240	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	210	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	180	Ω

[1] When supply voltages (V_{CC} - V_{EE}) near 2.0 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 2 V, it is recommended to use these devices only for transmitting digital signals.

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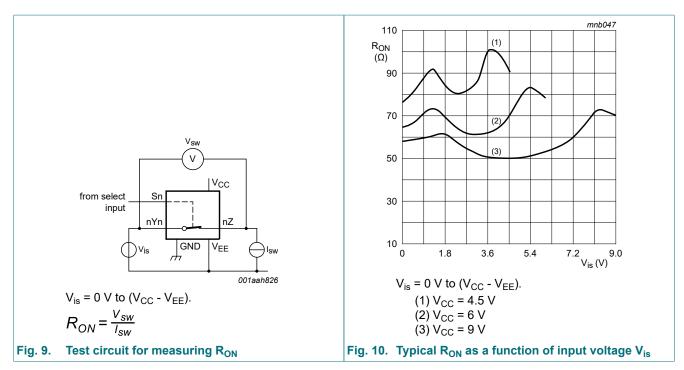


Table 7. Static characteristics for 74HC4053

Voltages are referenced to GND (ground = 0 V).

V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

Vos is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C	1	1		1	
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	1.2	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	0.8	0.5	V
	voltage	V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
		V _{CC} = 9.0 V	-	4.3	2.7	V
l _l	input leakage current	$V_{EE} = 0 V; V_I = V_{CC} \text{ or } GND$				
		V _{CC} = 6.0 V	-	-	±0.1	μA
		V _{CC} = 10.0 V	-	-	±0.2	μA
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 11</u>				
		per channel	-	-	±0.1	μA
		all channels	-	-	±0.1	μA
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 12</u>	-	-	±0.1	μA
I _{CC}	supply current	V_{EE} = 0 V; V _I = V _{CC} or GND; V _{is} = V _{EE} or V _{CC} ; V _{os} = V _{CC} or V _{EE}				
		V _{CC} = 6.0 V	-	-	8.0	μA
		V _{CC} = 10.0 V	-	-	16.0	μA
CI	input capacitance		-	3.5	-	pF

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{sw}	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	8	-	pF
T _{amb} = -4	40 °C to +85 °C					
VIH	HIGH-level input	V _{CC} = 2.0 V	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
I	input leakage	$V_{EE} = 0 V; V_I = V_{CC} \text{ or GND}$				
	current	V _{CC} = 6.0 V	-	-	±1.0	μA
		V _{CC} = 10.0 V	-	-	±2.0	μA
I _{S(OFF)}	(OFF) OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; Fig. 11				
		per channel	-	-	±1.0	μA
		all channels	-	-	±1.0	μA
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 12</u>	-	-	±1.0	μA
I _{CC}	supply current	V_{EE} = 0 V; V _I = V _{CC} or GND; V _{is} = V _{EE} or V _{CC} ; V _{os} = V _{CC} or V _{EE}				
		V _{CC} = 6.0 V	-	-	80.0	μA
		V _{CC} = 10.0 V	-	-	160.0	μA
T _{amb} = -4	40 °C to +125 °C					_
VIH	HIGH-level input	V _{CC} = 2.0 V	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
l _l	input leakage	$V_{EE} = 0 V; V_I = V_{CC} \text{ or GND}$				
	current	V _{CC} = 6.0 V	-	-	±1.0	μA
		V _{CC} = 10.0 V	-	-	±2.0	μA
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 10.0 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see <u>Fig. 11</u>				
		per channel	-	-	±1.0	μA
		all channels	-	-	±1.0	μA
I _{S(ON)}	ON-state leakage current	V _{CC} = 10.0 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see <u>Fig. 12</u>	-	-	±1.0	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CC}	supply current	V_{EE} = 0 V; V_I = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 6.0 V	-	-	160.0	μA
		V _{CC} = 10.0 V	-	-	320.0	μA

Table 8. Static characteristics for 74HCT4053

Voltages are referenced to GND (ground = 0 V).

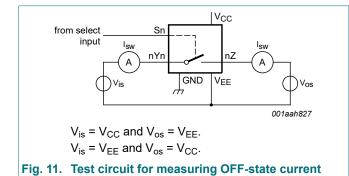
 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

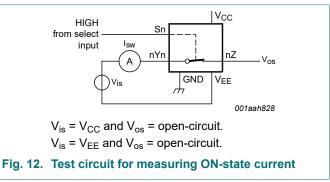
Vos is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C			1	1	
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
lı	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±0.1	μA
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±0.1	μA
		all channels	-	-	±0.1	μA
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±0.1	μA
I _{CC}	supply current	$V_{I} = V_{CC} \text{ or GND}; V_{is} = V_{EE} \text{ or } V_{CC}; V_{os} = V_{CC} \text{ or } V_{EE}$				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	8.0	μA
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	16.0	μA
ΔI _{CC}	additional supply current	per input; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V; $V_{EE} = 0 V$	-	50	180	μA
CI	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	8	-	pF
T _{amb} = -4	40 °C to +85 °C			•	•	
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±1.0	μA
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±1.0	μA
		all channels	-	-	±1.0	μA
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±1.0	μA
I _{CC}	supply current	$V_1 = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	80.0	μA
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	160.0	μA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
ΔI _{CC}	additional supply current	per input; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V; V _{EE} = 0 V	-	-	225	μA
T _{amb} = -4	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
lı	input leakage current	$V_{I} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	±1.0	μA
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±1.0	μA
		all channels	-	-	±1.0	μA
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±1.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	160.0	μA
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	320.0	μA
ΔI _{CC}	additional supply current	per input; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V; V _{EE} = 0 V	-	-	245	μA





11. Dynamic characteristics

Table 9. Dynamic characteristics for 74HC4053

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; for test circuit see Fig. 15.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

Vos is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Fig. 13</u> [1]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	15	60	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	5	12	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	4	10	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	4	8	ns

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = $\infty \Omega$; see <u>Fig. 14</u> [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	60	220	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	20	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	17	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	16	37	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	31	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Fig. 14 [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	75	220	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	25	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	21	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	20	37	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	31	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Fig. 14</u> [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	63	210	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	21	42	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	18	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	17	36	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	29	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see Fig. 14 [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	60	210	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	20	42	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	17	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	16	36	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	29	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to V_{CC} [4]	-	36	-	pF
$T_{amb} = -4$	40 °C to +85 °C			<u> </u>	<u> </u>	
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Fig. 13 [1]				
F -		$V_{CC} = 2.0 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	75	ns
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	15	ns
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	13	ns
		V _{CC} = 4.5 V; V _{FF} = -4.5 V	-	-	10	ns
t _{on}	turn-on time	E to V_{os} ; $R_L = \infty \Omega$; see Fig. 14 [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	275	ns
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	55	ns
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	47	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	39	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Fig. 14 [2]			-	
		$V_{CC} = 2.0 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	275	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	55	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	_	-	47	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$			39	ns

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Fig. 14</u> [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	53	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	45	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	36	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see Fig. 14 [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	53	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	45	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	36	ns
T _{amb} = -4	40 °C to +125 °C				1	
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Fig. 13</u> [1]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	90	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	12	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = $\infty \Omega$; see <u>Fig. 14</u> [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	330	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	56	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Fig. 14 [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	330	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	56	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Fig. 14</u> [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	315	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	63	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	54	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	44	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see Fig. 14 [3]				-
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	315	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	63	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	54	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	44	ns

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_{on} is the same as t_{PZH and} t_{PZL}.
[3] t_{off} is the same as t_{PHZ} and t_{PLZ}.
[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma \{(C_{L} + C_{sw}) \times V_{CC}^{2} \times f_{o}\} \text{ where:}$

 f_i = input frequency in MHz; f_o = output frequency in MHz;

N = number of inputs switching; Σ {(C_L + C_{sw}) × V_{CC}² × f_o} = sum of outputs;

 C_L = output load capacitance in pF; C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

Table 10. Dynamic characteristics for 74HCT4053

GND = 0 V; $t_r = t_f = 6 ns$; $C_L = 50 pF$; for test circuit see Fig. 15.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	25 °C						
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Fig. 13</u>	[1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	5	12	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	4	8	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = 1 kΩ; see <u>Fig. 14</u>	[2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	27	48	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	23	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	16	34	ns
		Sn to V_{os} ; R_L = 1 k Ω ; see <u>Fig. 14</u>	[2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	25	48	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	21	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	16	34	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 kΩ; see <u>Fig. 14</u>	[3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	24	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	20	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	15	31	ns
		Sn to V_{os} ; R_L = 1 k Ω ; see <u>Fig. 14</u>	[3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	22	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	19	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	15	31	ns
C _{PD}	power dissipation capacitance	per switch; V_I = GND to V_{CC} - 1.5 V	[4]	-	36	-	pF
T _{amb} = -	40 °C to +85 °C				1	1	
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Fig. 13</u>	[1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	10	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = 1 kΩ; see <u>Fig. 14</u>	[2]				_
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	60	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	43	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see Fig. 14	[2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	60	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	43	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 kΩ; see <u>Fig. 14</u>	[3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	55	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	39	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Fig. 14	[3]				+
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	55	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	39	ns

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +125 °C		1	-		
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Fig. 13 [1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	12	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Fig. 14</u> [2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	72	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	51	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Fig. 14 [2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	72	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	51	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Fig. 14</u> [3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Fig. 14 [3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns

 t_{pd} is the same as t_{PHL} and $t_{\text{PLH}}.$ [1]

[2] t_{on} is the same as t_{PZH and} t_{PZL}.

 t_{off} is the same as t_{PHZ} and t_{PLZ} . [3]

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

 f_i = input frequency in MHz; f_o = output frequency in MHz;

N = number of inputs switching; Σ {(C_L + C_{sw}) × V_{CC}² × f_o} = sum of outputs;

 C_L = output load capacitance in pF; C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

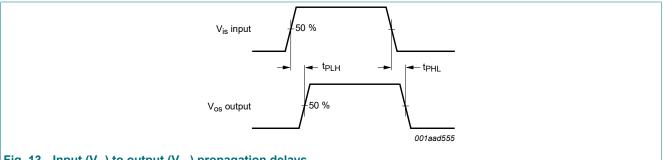


Fig. 13. Input (V_{is}) to output (V_{os}) propagation delays

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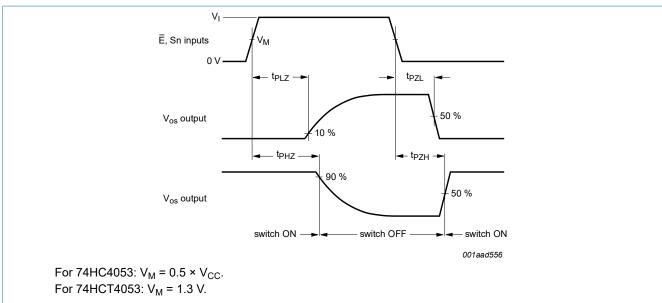


Fig. 14. Turn-on and turn-off times

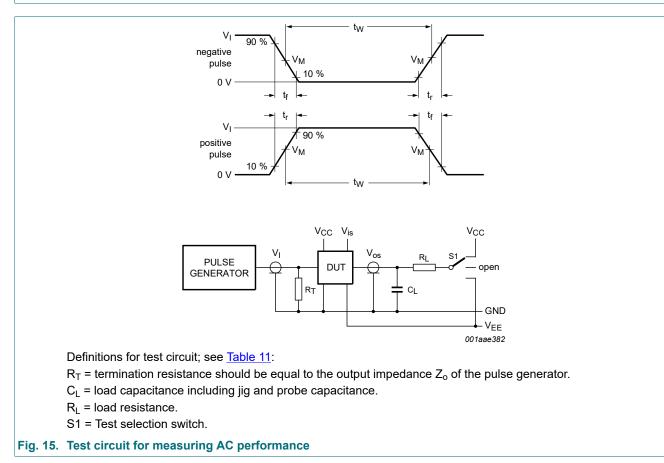


Table 11. Test data

Test	Input				Load	Load		
	V _I [1]	V _{is}	t _r , t _f	t _r , t _f		RL		
			at f _{max}	other [2]				
t _{PHL} , t _{PLH}	V _{CC}	pulse	< 2 ns	6 ns	50 pF	1 kΩ	open	
t _{PZH} , t _{PHZ}	V _{CC}	V _{CC}	< 2 ns	6 ns	50 pF	1 kΩ	V _{EE}	
t _{PZL} , t _{PLZ}	V _{CC}	V _{EE}	< 2 ns	6 ns	50 pF	1 kΩ	V _{CC}	

[1] For 74HCT4053: V_I = 3 V

[2] $t_r = t_f = 6$ ns; when measuring f_{max} , there is no constraint to t_r and t_f with 50 % duty factor.

11.1. Additional dynamic characteristics

Table 12. Additional dynamic characteristics

Recommended conditions and typical values; GND = 0 V; $T_{amb} = 25 °C$; $C_L = 50 pF$. V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nYn or nZ, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
d _{sin}	sine-wave distortion	$f_i = 1 \text{ kHz}; R_L = 10 \text{ k}\Omega; \text{ see } \frac{\text{Fig. 16}}{1000}$				
		V _{is} = 4.0 V (p-p); V _{CC} = 2.25 V; V _{EE} = -2.25 V	-	0.04	-	%
		V _{is} = 8.0 V (p-p); V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	0.02	-	%
		f _i = 10 kHz; R _L = 10 kΩ; see <u>Fig. 16</u>				
		V _{is} = 4.0 V (p-p); V _{CC} = 2.25 V; V _{EE} = -2.25 V	-	0.12	-	%
		V _{is} = 8.0 V (p-p); V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	0.06	-	%
α_{iso}	isolation (OFF-state)	$R_L = 600 \Omega; f_i = 1 MHz; see Fig. 17$				
		$V_{CC} = 2.25 \text{ V}; \text{ V}_{EE} = -2.25 \text{ V}$ [1]	-	-50	-	dB
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{EE} = -4.5 \text{ V}$ [1]	-	-50	-	dB
Xtalk	crosstalk	between two switches/multiplexers; R_L = 600 Ω ; f_i = 1 MHz; see Fig. 18				
		$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$ [1]	-	-60	-	dB
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$ [1]	-	-60	-	dB
V _{ct}	crosstalk voltage	peak-to-peak value; between control and any switch; $R_L = 600 \Omega$; $f_i = 1 MHz$; \overline{E} or Sn square wave between V _{CC} and GND; $t_r = t_f = 6 ns$; see Fig. 19				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	110	-	mV
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	220	-	mV
f _(-3dB)	-3 dB frequency	R _L = 50 Ω; see <u>Fig. 20</u>				
	response	V _{CC} = 2.25 V; V _{EE} = -2.25 V [2]	-	160	-	MHz
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{EE} = -4.5 \text{ V}$ [2]	-	170	-	MHz

[1] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).

[2] Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).

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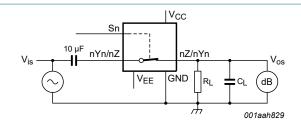
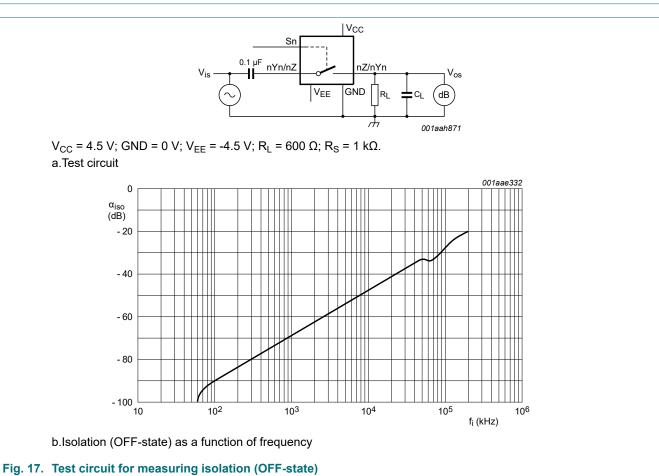
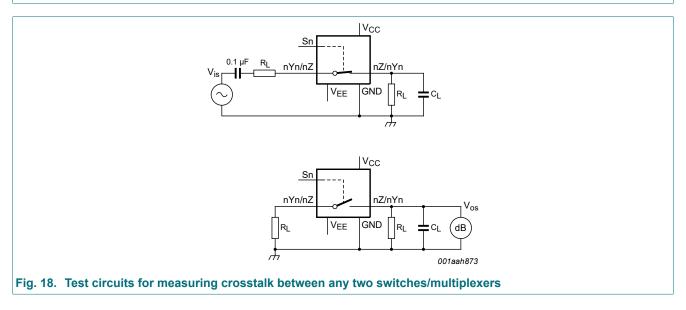
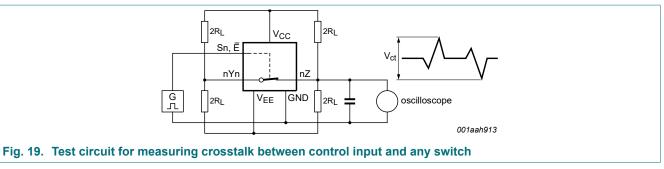


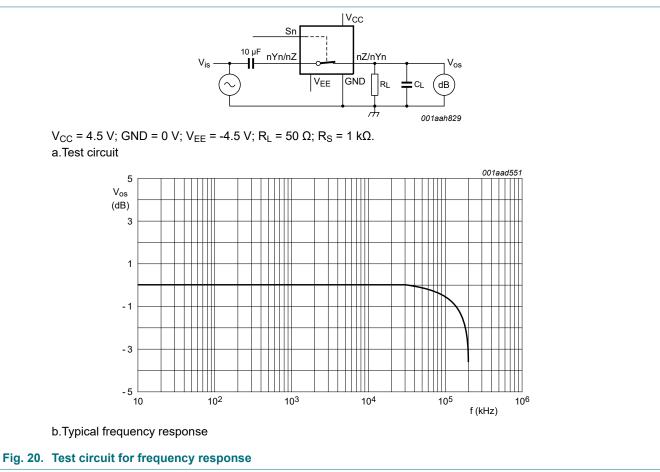
Fig. 16. Test circuit for measuring sine-wave distortion





Triple 2-channel analog multiplexer/demultiplexer





12. Package outline

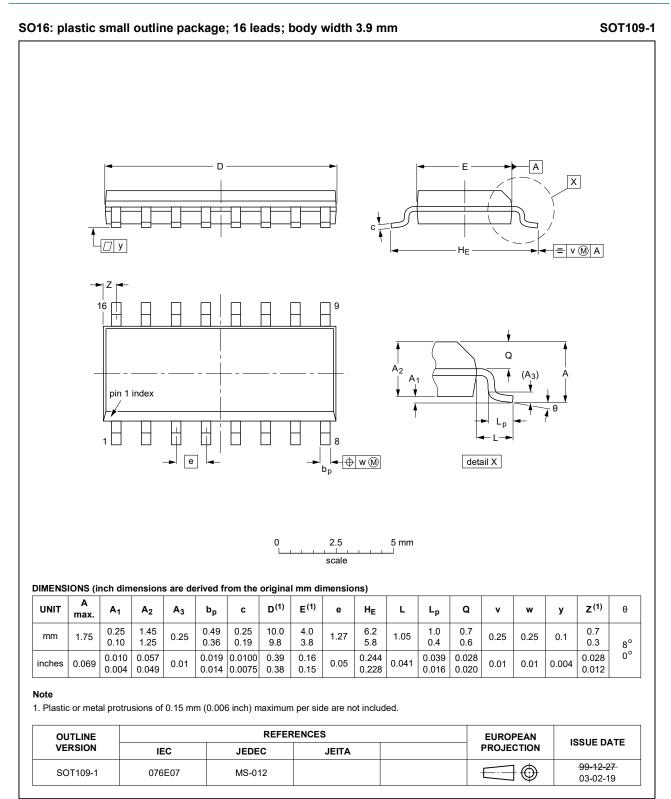


Fig. 21. Package outline SOT109-1 (SO16)

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Triple 2-channel analog multiplexer/demultiplexer

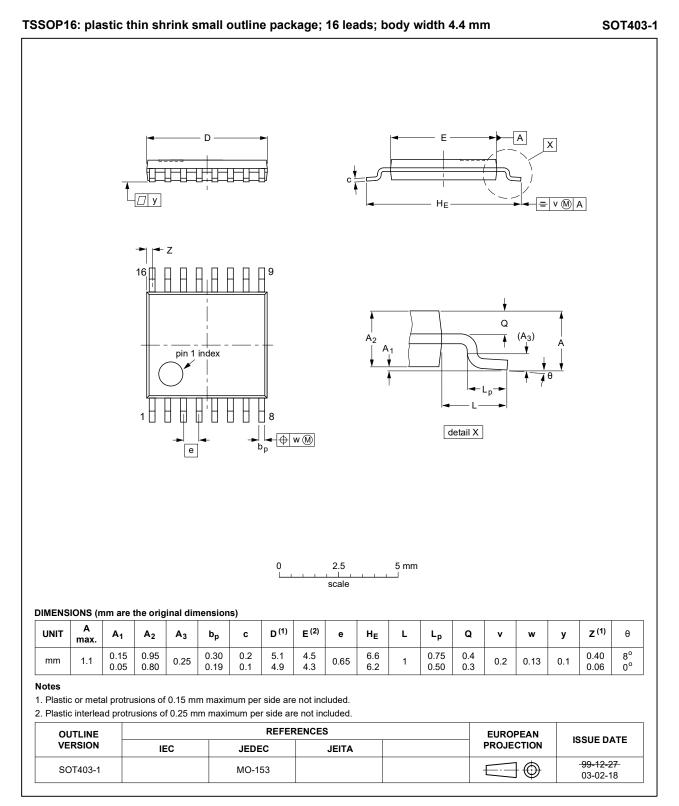
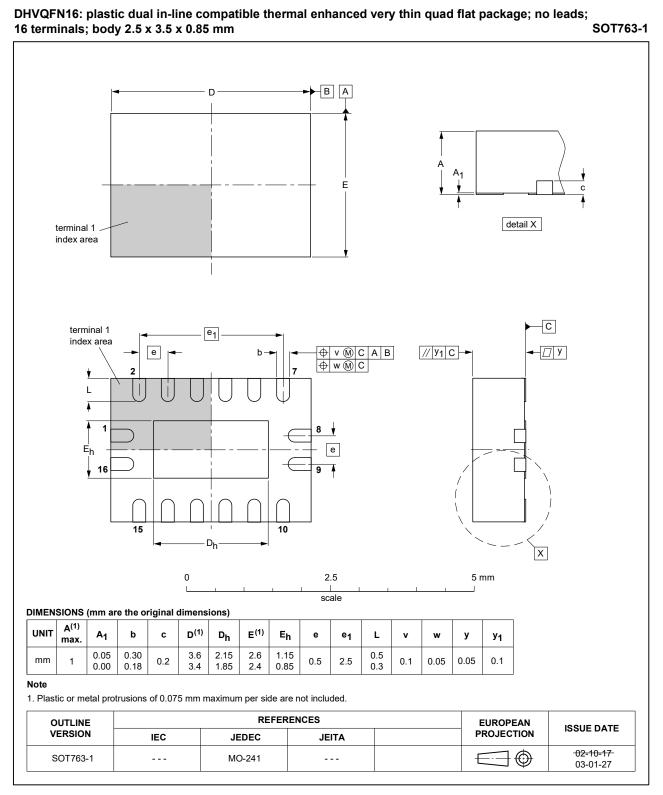


Fig. 22. Package outline SOT403-1 (TSSOP16)

⁷⁴HC_HCT4053

Triple 2-channel analog multiplexer/demultiplexer





13. Abbreviations

Table 13. Abbreviations					
Acronym	Description				
CDM	Charged Device Model				
ESD	ElectroStatic Discharge				
НВМ	Human Body Model				
MM	Machine Model				

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74HC_HCT4053 v.11	20210909	Product data sheet	-	74HC_HCT4053 v.10				
Modifications:	Type number <u>Section 2</u> up	er 74HC4053DB (SOT338- pdated.	1/SSOP16) remo	ved.				
74HC_HCT4053 v.10	20200305	Product data sheet	-	74HC_HCT4053 v.9				
Modifications:	guidelines of Legal texts Type number	 Legal texts have been adapted to the new company name where appropriate. 						
74HC_HCT4053 v.9	20160210	Product data sheet	-	74HC_HCT4053 v.8				
Modifications:	Type number	ers 74HC4053N and 74HC	T4053N (SOT38-	4) removed.				
74HC_HCT4053 v.8	20120719	Product data sheet	-	74HC_HCT4053 v.7				
Modifications:	CDM addec	to features.						
74HC_HCT4053 v.7	20111213	Product data sheet	-	74HC_HCT4053 v.6				
Modifications:	Legal pages	s updated.						
74HC_HCT4053 v.6	20110511	Product data sheet	-	74HC_HCT4053 v.5				
74HC_HCT4053 v.5	20110118	Product data sheet	-	74HC_HCT4053 v.4				
74HC_HCT4053 v.4	20060509	Product data sheet	-	74HC_HCT4053 v.3				
74HC_HCT4053 v.3	20060315	Product data sheet	-	74HC_HCT4053_CNV v.2				
74HC_HCT4053_CNV v.2	19901201	Product specification	-	-				

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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